

NEC

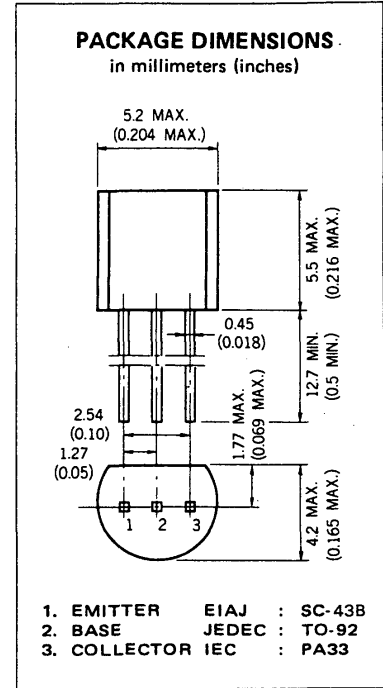
PNP SILICON TRANSISTOR 2SA1206

DESCRIPTION The 2SA1206 is designed for general purpose amplifier and high speed switching applications.

- FEATURES**
- High Frequency Current Gain.
 - High Speed Switching.
 - Small Output Capacitance.
 - Low Collector Saturation Voltage.

ABSOLUTE MAXIMUM RATINGS (Ta=25 °C)

- Maximum Temperatures
- Storage Temperature -55 to +150 °C
 - Junction Temperature 150 °C Maximum
- Maximum Power Dissipation (Ta=25 °C)
- Total Power Dissipation 600 mW
- Maximum Voltages and Currents (Ta=25 °C)
- V_{CB0} Collector to Base Voltage -15 V
 - V_{CEO} Collector to Emitter Voltage -15 V
 - V_{EBO} Emitter to Base Voltage -4.5 V
 - I_C Collector Current (D.C.) -50 mA
 - I_C Collector Current (pulse) * -100 mA
- * PW ≤ 2 ms, duty cycle ≤ 50 %

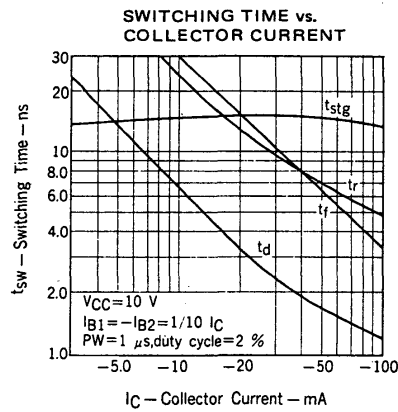
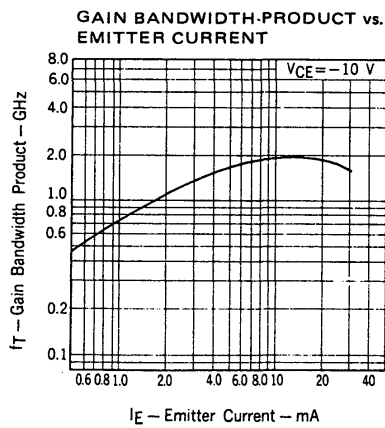
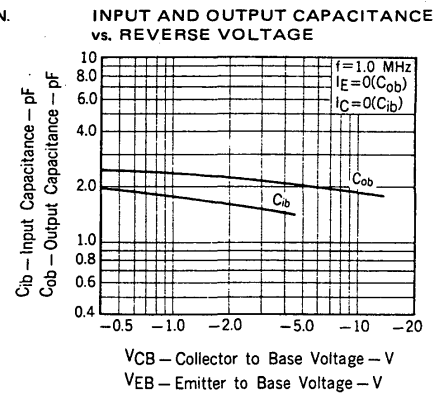
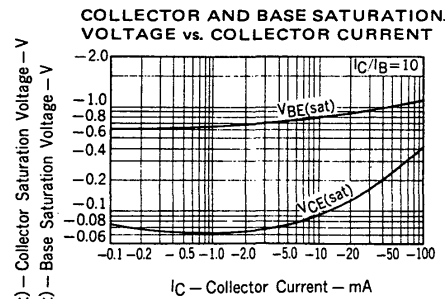
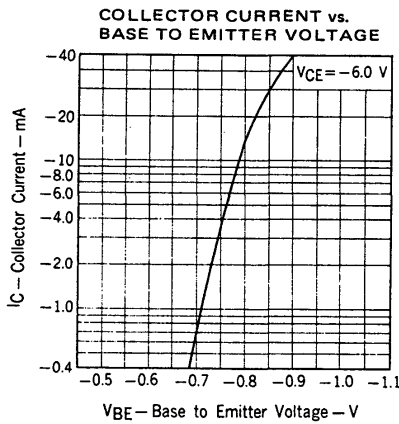
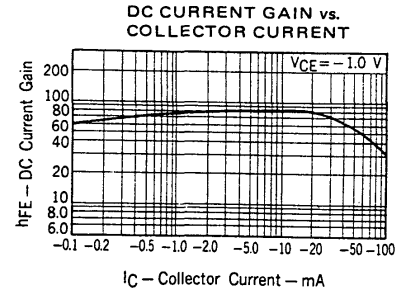
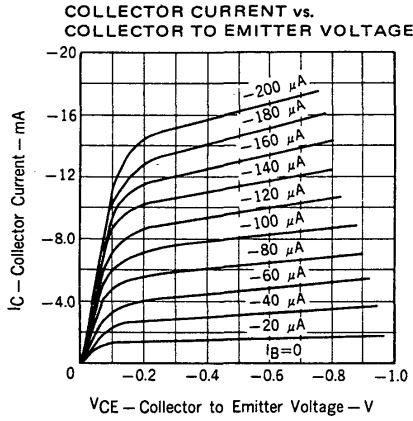
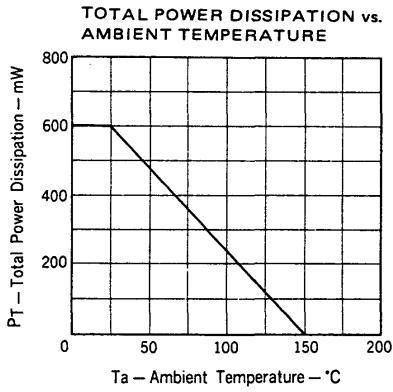


ELECTRICAL CHARACTERISTICS (Ta=25 °C)

SYMBOL	CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
t _{on}	Turn-on Time		9.0	20	ns	See test circuit.
t _{off}	Turn-off Time		19	40	ns	See test circuit.
t _{stg}	Storage Time		16	40	ns	See test circuit.
f _T	Gain Bandwidth Product	800	1800		MHz	V _{CE} = -10 V, I _E = 10 mA, f = 100 MHz
C _{ob}	Output Capacitance		2.0	3.0	pF	V _{CB} = -5.0 V, I _E = 0, f = 1 MHz
h _{FE1} *	DC Current Gain	50	80	150	-	V _{CE} = -1.0 V, I _C = -10 mA
h _{FE2} *	DC Current Gain	30	70		-	V _{CE} = -1.0 V, I _C = -1.0 mA
V _{CE(sat)} *	Collector Saturation Voltage		-0.09	-0.20	V	I _C = -10 mA, I _B = -1.0 mA
V _{BE(sat)} *	Base Saturation Voltage		-0.80	-0.95	V	I _C = -10 mA, I _B = -1.0 mA
I _{CBO}	Collector Cutoff Current			-0.1	μA	V _{CB} = -8.0 V, I _E = 0
I _{EBO}	Emitter Cutoff Current			-0.1	μA	V _{EB} = -3.0 V, I _C = 0

* Pulsed PW ≤ 350 μs, duty cycle ≤ 2 %

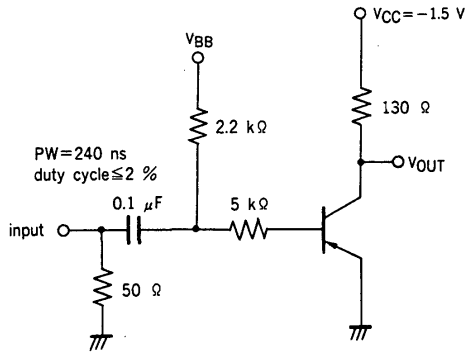
TYPICAL CHARACTERISTICS (Ta = 25 °C)



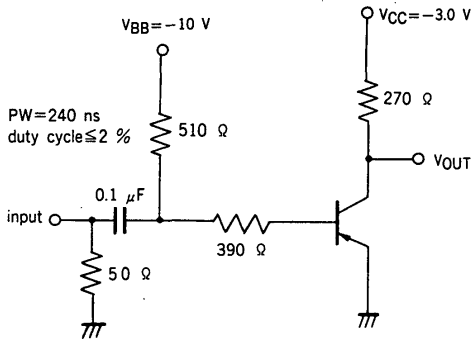
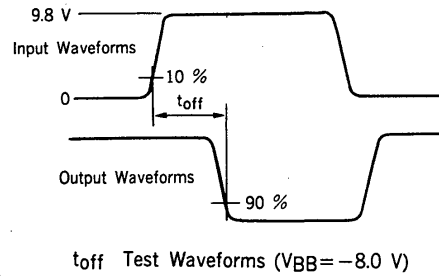
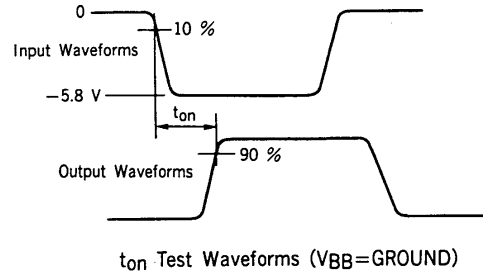
2SA1206

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SWITCHING TIME TEST CIRCUIT



ton, toff Test Circuit



tstg Test Circuit

